

NPN Plastic-Encapsulate

Transistors

Mechanical Data

· Case: SOT-23 Molded plastic

• Epoxy: UL94V-O rate flame retardant

· RoHS compliant package

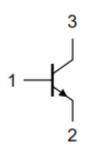
Packing & Order Information

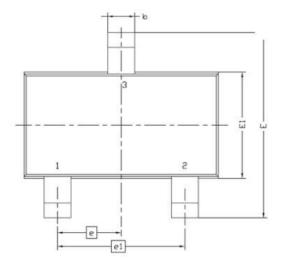
3,000/Reel

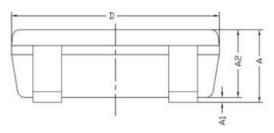


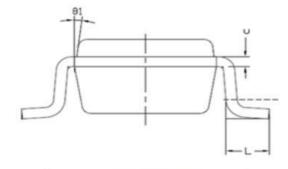
RoHS COMPLIANT

Graphic symbol









Cumbal	MILLIMETERS			
Symbol	MIN	MAX		
Α	0.8	1.2		
A1	0	0.1		
A2	0.7	1.1		
b	0.3	0.5		
С	0.1	0.2		
D	2.7	3.1		
E	2.6	3		
E1	1.4	1.8		
е	0.95 BSC			
e1	1.9 BSC			
L	0.3	0.6		
θ1	7° NOM			



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MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

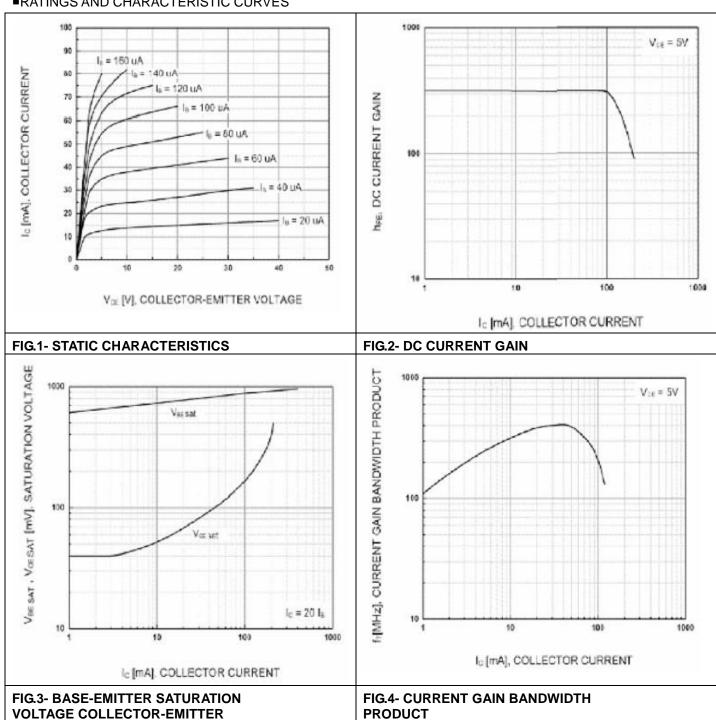
MAXIMUM RATINGS (Ta=25°C unless otherwise noted)						
Symbol	Parameter	Value	Unit			
V_{CBO}	Collector-Base Voltage	50	V			
V_{CEO}	Collector-Emitter Voltage	45	V			
V_{EBO}	Emitter-Base Voltage	5	V			
I _C	Collector Current	0.1	А			
Pc	Collector Power Dissipation	0.2	W			
Tj	Junction Temperature	150	°C			
Tstg	Storage Temperature	-55 to +150	°C			

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified									
Symbol	Parameter	Test Conditions	MIN	TYP	MAX	UNIT			
$V_{(BR)CBO} \\$	Collector-base breakdown voltage	$I_C = 100 \mu A$, $I_E = 0$	50			V			
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	$I_{C} = 0.1 \text{ mA}$, $I_{B} = 0$	45			V			
$V_{(BR)EBO}$	Emitter-base breakdown voltage	$I_E = 100 \mu A , I_C = 0$	5			V			
I _{CBO}	Collector cut-off current	$V_{CB} = 50 \text{ V}$, $I_E = 0$			0.1	μA			
I _{CEO}	Collector cut-off current	$V_{CB} = 35 \text{ V}$, $I_E = 0$			0.1	μA			
I _{EBO}	Emitter cut-off current	$V_{EB} = 3 \text{ V}$, $I_{C} = 0$			0.1	μA			
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}$, $I_C = 1 \text{ mA}$	200		1000				
$V_{\text{CE(sat)}}$	Collector-emitter saturation voltage	$I_{C} = 100 \text{ mA}$, $I_{B} = 5 \text{ mA}$			0.3	V			
$V_{\text{BE(sat)}}$	Base-Emitter Saturation Voltage	$I_{C} = 100 \text{ mA}$, $I_{B} = 5 \text{ mA}$			1.0	V			
f _T	Transition frequency	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$ f = 30 MHz	150			MHz			



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■RATINGS AND CHARACTERISTIC CURVES



SATURATION VOLATAGE



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